

Photocoupler

Part Name: LA211

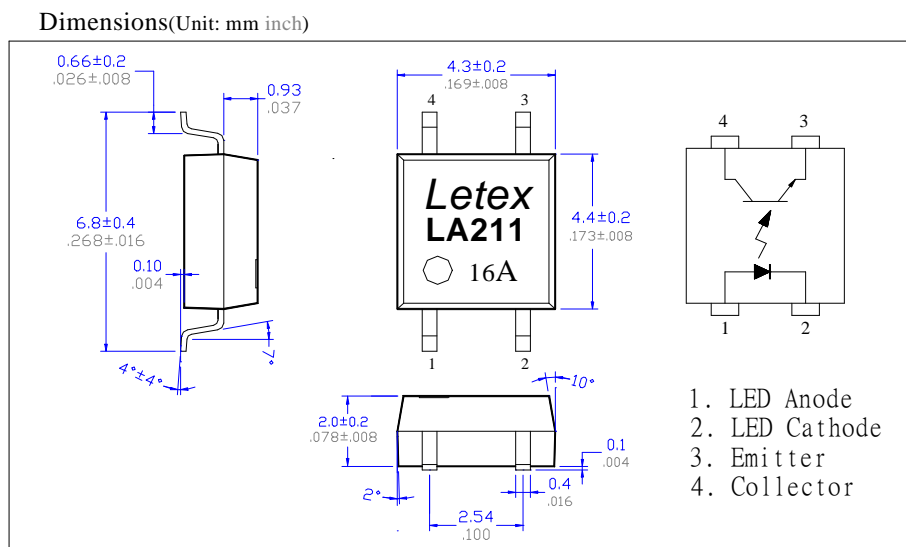
LA211 photocoupler is an optically coupled pair employing a GaAs infrared LED and a silicon NPN phototransistor.

Features

- SOP package 4 Pin type in miniature design
- 80% minimum current transfer ratio
- 1500Vrms Input/Output isolation

Applications

- Computer terminals
- System appliances
- Signal transmission between circuits of different potentials



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Absolute Maximum Ratings (Ambient Temperature: 25°C)

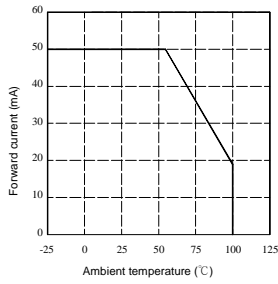
Item		Symbol	Rating	Units	Note
Input	Forward Current	IF	50	mA	
	Reverse Voltage	VR	5	V	
	Peak Forward Current	IFP	1	A	
Output	Collector to Emitter Voltage	Vceo	40	V	Ic=1mA, IB=0
	Emitter to Collector Voltage	Veco	6	V	IE=100μA, IB=0
	Collector Current	Ic	50	mA	
	Power Dissipation	Pc	150	mW	
I/O Breakdown Voltage		VI/O	1500	Vrms	RH=60%, 1min
Power Dissipation		PD	200	mW	
Storage Temperature		Tstg	-55 to +125	°C	
Operating Temperature		Top	-55 to +100	°C	
Soldering Temperature		TSol	260	°C	10 seconds max.

Electrical Specifications (Ambient Temperature: 25°C)

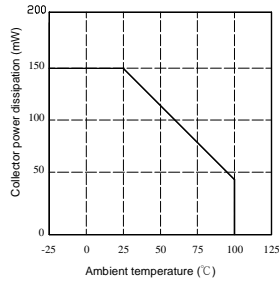
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions	
Input	Forward Voltage	VF		1.2	1.4	V	IF=20mA	
	Reverse Current	IR			10	μA	VR=5V	
	Junction Capacitance	Ct		25		pF	V=0, f=1.0MHz	
Output	C-E Breakdown Voltage	Vceo	35			V	Ic=0.5mA	
	E-C Breakdown Voltage	Veco	5			V	Ie=0.1mA	
	Collector Dark Current	Iceo			100	nA	Vce=10V, IF=0	
Coupled	Current Transfer Ratio	BIN GRADE					IF=5mA, Vce=5V	
		A	80					160
		B	130					260
		C	200					400
		D	300		600			
	Collector Saturation Voltage	Vce(sat)			0.4	V	IF=10mA, Ic=1mA	
	Isolation Resistance	Ri/o	10 ⁹			Ω	V=500V DC	
	Isolation Capacitance	Ci/o		1.0		pF	V=0, f=1.0MHz	
Rise Time	tr			3	μs	Vce=5V, Ic=2mA,		
Fall Time	tf			3	μs	RL=100Ω		

Photocoupler Reference Data

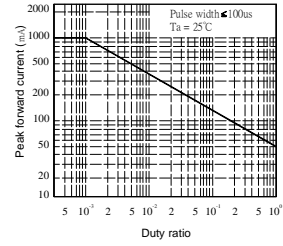
Forward current Vs. Ambient temperature



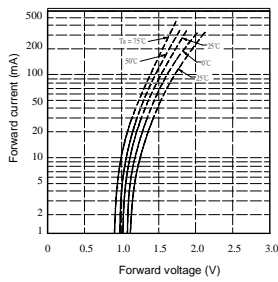
Collector power dissipation Vs. Ambient temperature



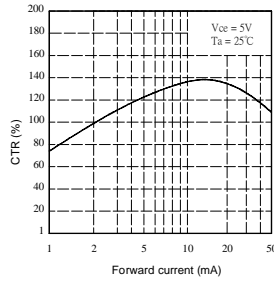
Peak forward current Vs. Duty ratio



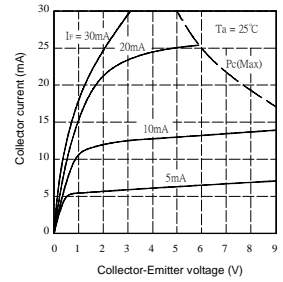
Forward current Vs. Forward voltage



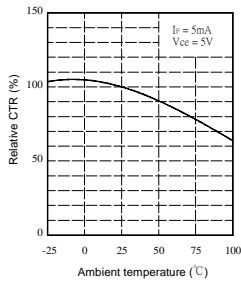
Current transfer ratio Vs. Forward current



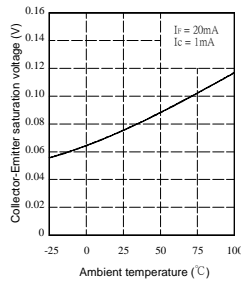
Collector current Vs. Collector-Emitter voltage



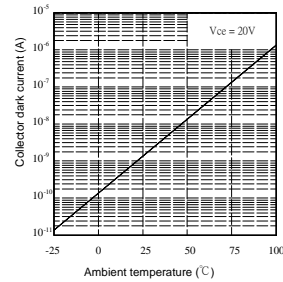
Relative CTR Vs. Ambient temperature



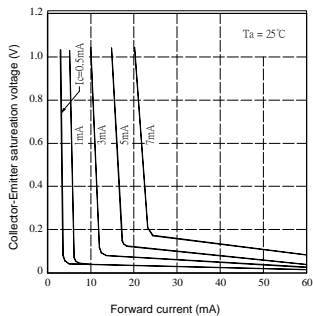
Collector-Emitter saturation voltage Vs. Ambient temperature



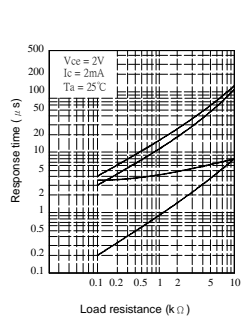
Collector dark current Vs. Ambient temperature



Collector-Emitter saturation voltage Vs. Forward current



Response time Vs. Load resistance



Test circuit for response time

